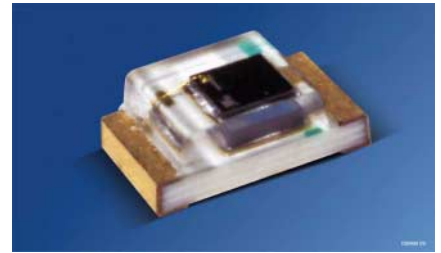


**NPN-Si-Fototransistor mit  $V_{\lambda}$  Charakteristik**  
**Silicon NPN Phototransistor with  $V_{\lambda}$  Characteristics**  
**Lead (Pb) Free Product - RoHS Compliant**

**SFH 3710**



**Wesentliche Merkmale**

- Sehr kleines SMT Gehäuse
- Angepaßt an die Augenempfindlichkeit ( $V_{\lambda}$ )

**Anwendungen**

- Umgebungslicht-Detektor
- Beleuchtungsmesser
- Dimmungssensor für Hintergrundbeleuchtung
- „Messen/Steuern/Regeln“

**Features**

- Very small SMT package
- Adapted to human eye sensitivity ( $V_{\lambda}$ )

**Applications**

- Ambient light detector
- Exposure meter for daylight and artificial light
- Sensor for Backlight-Dimming
- For control and drive circuits

Typ Type	Bestellnummer Ordering Code	Fotostrom , $E_e = 10 \mu\text{W}/\text{cm}^2$ , $\lambda = 560 \text{ nm}$ , $V_{\text{CE}} = 5 \text{ V}$ Photocurrent $I_{\text{pce}} (\mu\text{A})$
SFH 3710	Q65110A3107	2.5...12.5
SFH 3710-2/3	Q65110A3512	2.5...8.0
SFH 3710-3/4	Q65110A3511	4.0...12.5

Einzelgruppen auf Anfrage / single bins on request

**Grenzwerte** ( $T_A = 25\text{ °C}$ )**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}; T_{stg}$	- 40 ... + 85	°C
Kollektor-Emitterspannung Collector-emitter voltage	$V_{CE}$	5.5	V
Kollektorstrom Collector current	$I_C$	20	mA
Emitter-Kollektorspannung Emitter-collector voltage	$V_{EC}$	0.5	V

**Kennwerte** ( $T_A = 25\text{ °C}$ )**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{Smax}$	570	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von $S_{max}$ Spectral range of sensitivity $S = 10\%$ of $S_{max}$	$\lambda$	350 ... 950	nm
Bestrahlungsempfindliche Fläche Radiant sensitive area	$A$	0.29	mm <sup>2</sup>
Abmessung der Chipfläche Dimensions of chip area	$L \times B$ $L \times W$	$0.75 \times 0.75$	mm × mm
Halbwinkel Half angle	$\varphi$	± 60	Grad. deg.
Kapazität, $V_{CE} = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$ Capacitance	$C_{CE}$	4	pF
Dunkelstrom Dark current $V_R = 5\text{ V}$	$I_{CEO}$	3 (< 50)	nA
Temperaturkoeffizient Temperature Coefficient Normlicht A / Standard Light A $\lambda = 550\text{ nm}$	$TK$ $TK_{550\text{ nm}}$	0.9 0.78	%/K %/K

Kennwerte ( $T_A = 25\text{ °C}$ )

## Characteristics

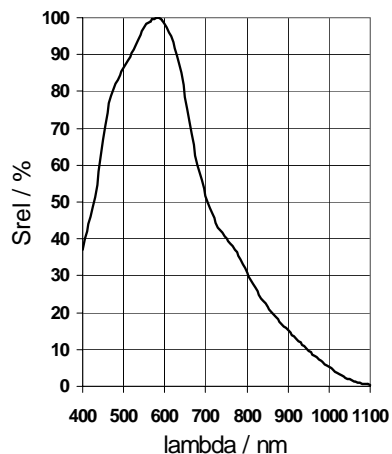
Bezeichnung Parameter	Symbol Symbol	Wert Value			Einheit Unit
		-2	-3	-4	
Fotostrom Photocurrent $E_e = 10\text{ }\mu\text{W}/\text{cm}^2$ , $\lambda = 560\text{ nm}$ , $V_{CE} = 5\text{ V}$ $E_v = 1000\text{ lx}$ , Normlicht/Standard light A	$I_{PCE}$	2.5...5 220	4...8 350	6.3...12.5 570	$\mu\text{A}$ $\mu\text{A}$
Kollektor-Emitter-Sättigungsspannung Collector-emitter saturation voltage $I_C = I_{PCEmin}^{1)} \times 0.3$ , $E_e = 10\text{ }\mu\text{W}/\text{cm}^2$ , $\lambda = 560\text{ nm}$	$V_{CEsat}$	100	100	100	mV

<sup>1)</sup>  $I_{PCEmin}$  ist der minimale Fotostrom der jeweiligen Gruppe

<sup>1)</sup>  $I_{PCEmin}$  is the min. photocurrent of the specified group

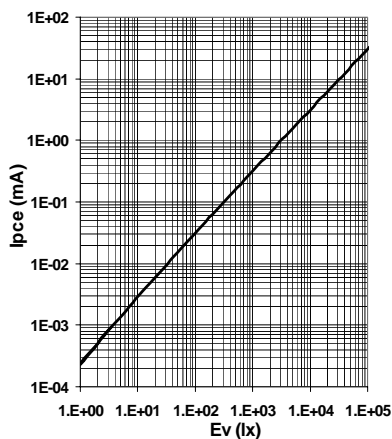
**Relative Spectral Sensitivity**

$S_{rel} = f(\lambda)$



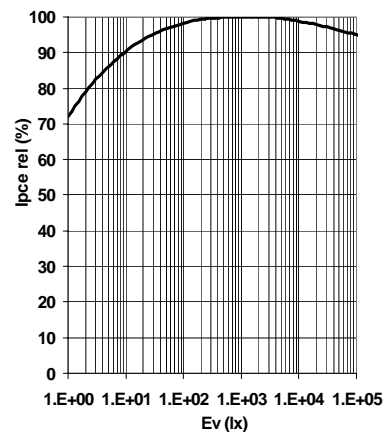
**Photocurrent**

$I_{PCE} = f(E_V), V_{CE} = 5 V$



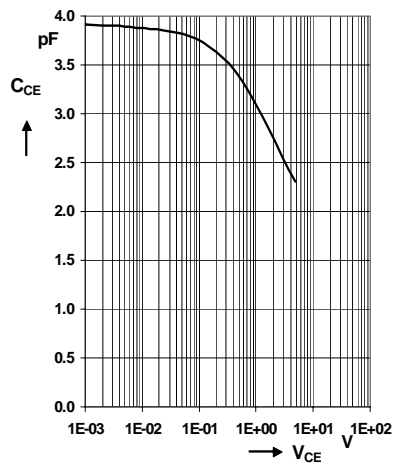
**Photocurrent**

$I_{PCE} = f(E_V), V_{CE} = 5 V$   
normalized to 1000lx



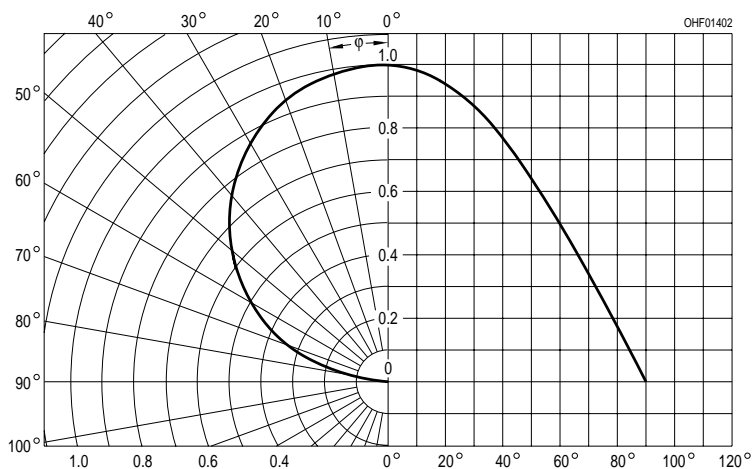
**Collector-Emitter Capacitance**

$C_{CE} = f(V_{CE})$

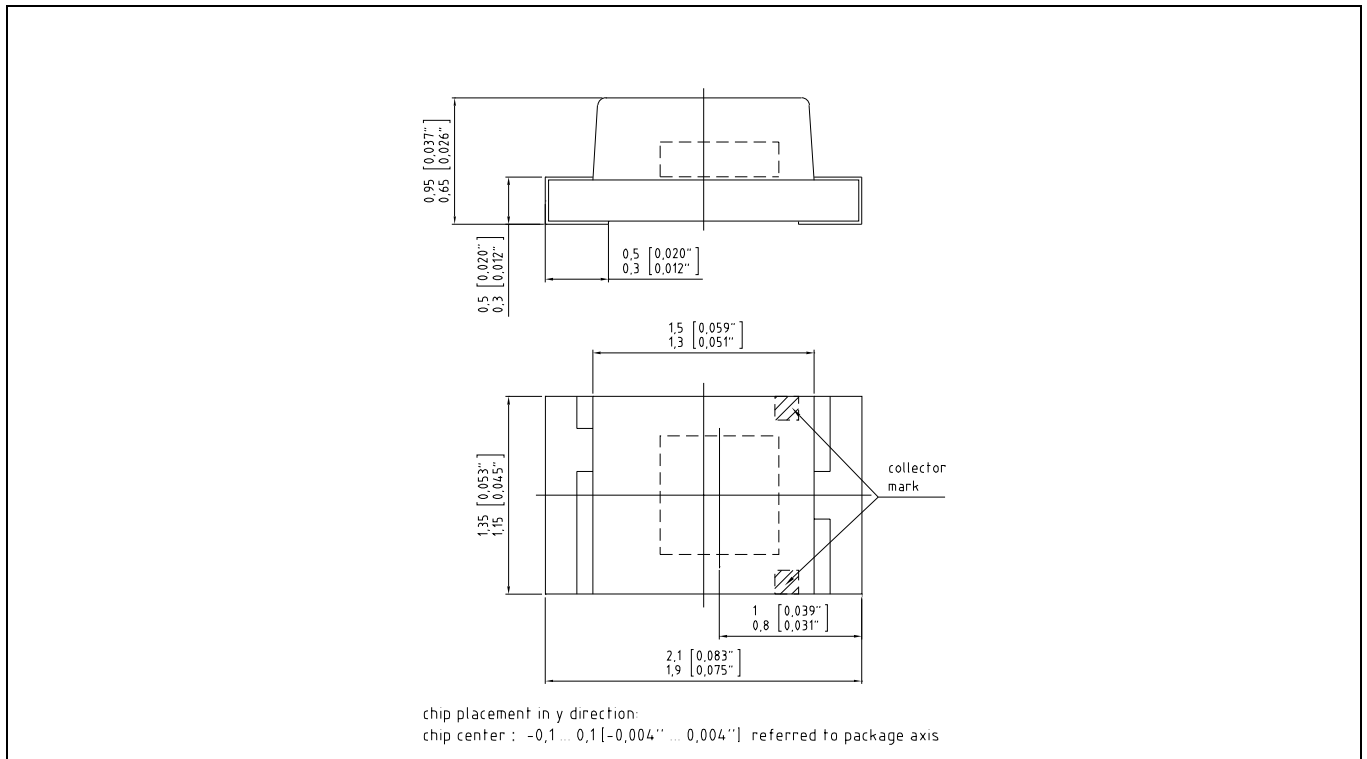


**Directional Characteristics**

$S_{rel} = f(\varphi)$

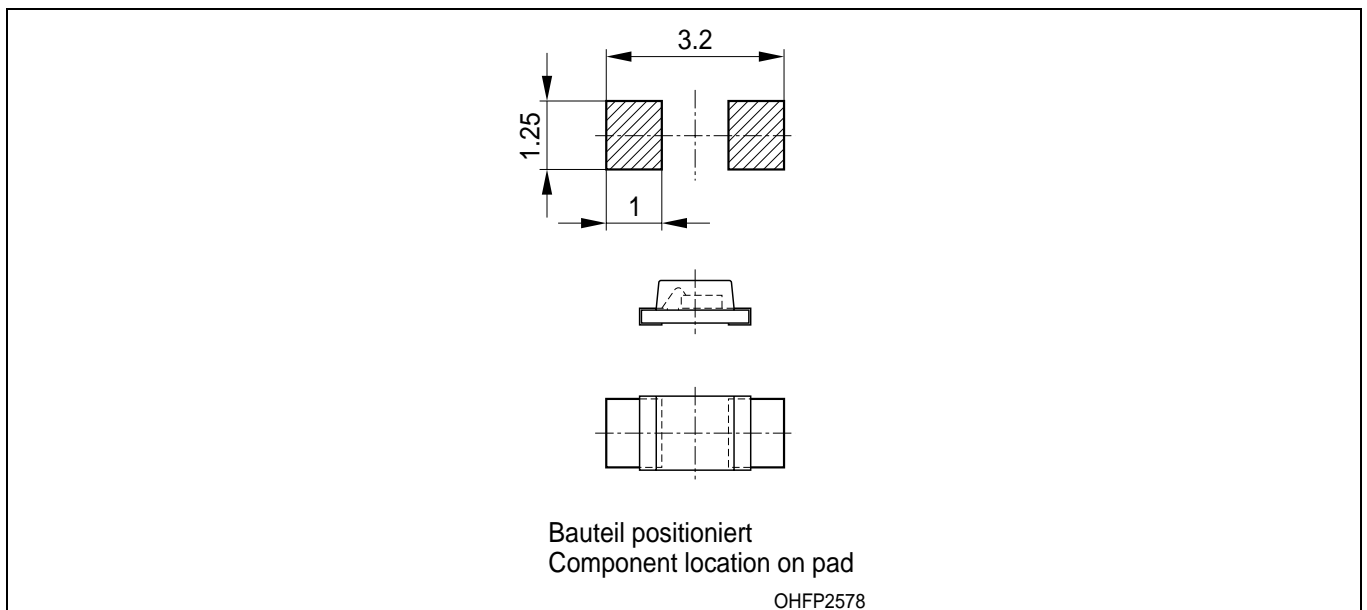


**Maßzeichnung  
Package Outlines**



Maße in mm (inch) / Dimensions in mm (inch)

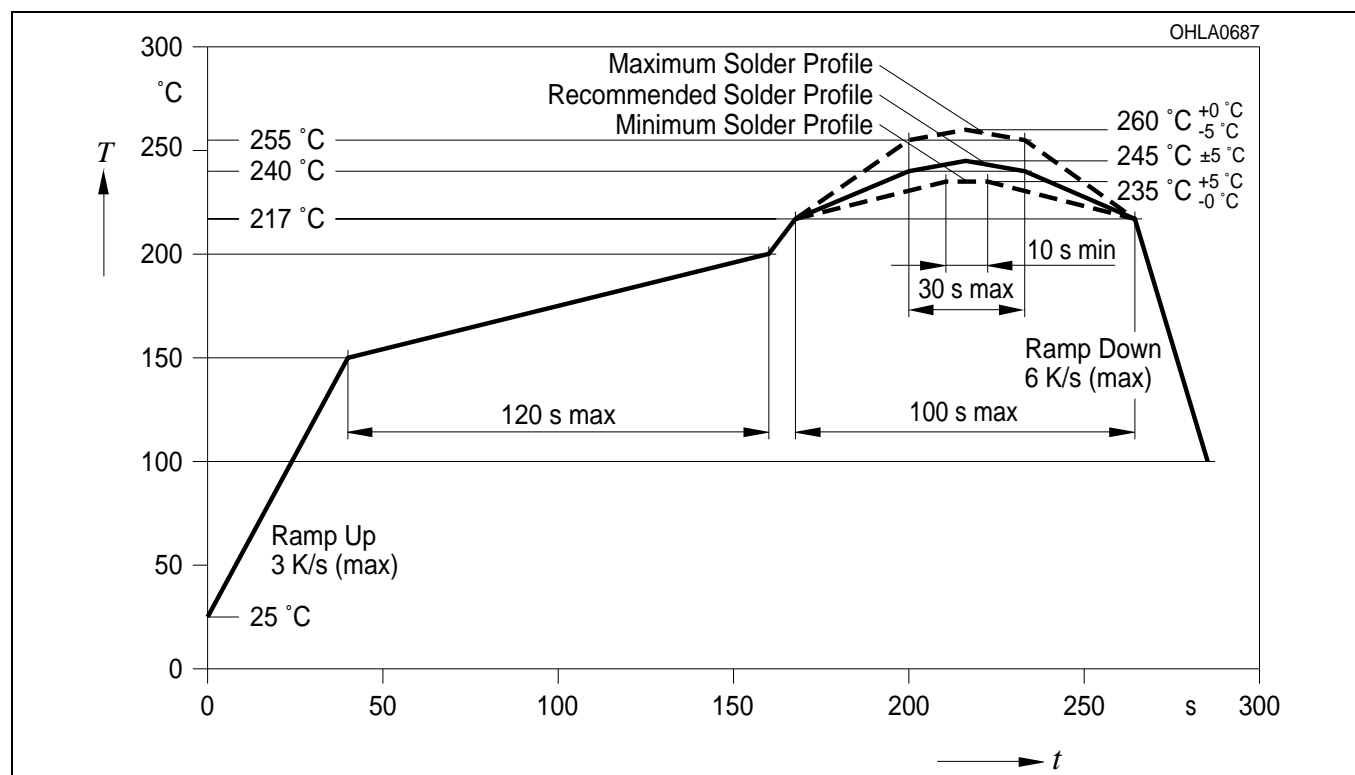
**Empfohlenes Lötpaddesign  
Recommended Solderpad Design**



Maße in mm / Dimensions in mm

**Lötbedingungen**  
**Soldering Conditions**  
**Reflow Lötprofil für bleifreies Löten**  
**Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 2  
 Preconditioning acc. to JEDEC Level 2  
 (nach J-STD-020C)  
 (acc. to J-STD-020C)



Published by  
**OSRAM Opto Semiconductors GmbH**  
 Wernerwerkstrasse 2, D-93049 Regensburg

[www.osram-os.com](http://www.osram-os.com)

© All Rights Reserved.

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization.

**Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

**Components used in life-support devices or systems must be expressly authorized for such purpose!** Critical components<sup>1</sup>, may only be used in life-support devices or systems<sup>2</sup> with the express written approval of OSRAM OS.

<sup>1</sup> A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or effectiveness of that device or system.

<sup>2</sup> Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.

EU RoHS and China RoHS compliant product



此产品符合欧盟 RoHS 指令的要求；

按照中国的相关法规和标准，不含有毒有害物质或元素。